

IFW



Docket No. TIP485US

TI-35362

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

re **PATENT** application of:

Applicant: Binghua Hu et al.

Application No.: 10/712,455

For: METHOD TO MANUFACTURE LDMOS TRANSISTORS WITH  
IMPROVED THRESHOLD VOLTAGE CONTROL

Filing Date: November 12, 2003

Examiner: Laura M. Schillinger

Art Unit: 2813

**REPLY TO OFFICE ACTION DATED AUGUST 9, 2005**

Mail Stop Amendment  
Assistant Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Examiner:

Favorable reconsideration of the above-identified application is respectfully  
requested in view of the following amendments and remarks.